

## 1550nm DFB 40mW High Power Butterfly Laser

### 1. Features:

- High optical output power;
- Built-in isolator;
- FC/APC SM fiber;
- High side-mode suppression ratio.

**OC-48 Pinout Compatible.**

### 2. Applications:

- Testing system;
- High optical power system.

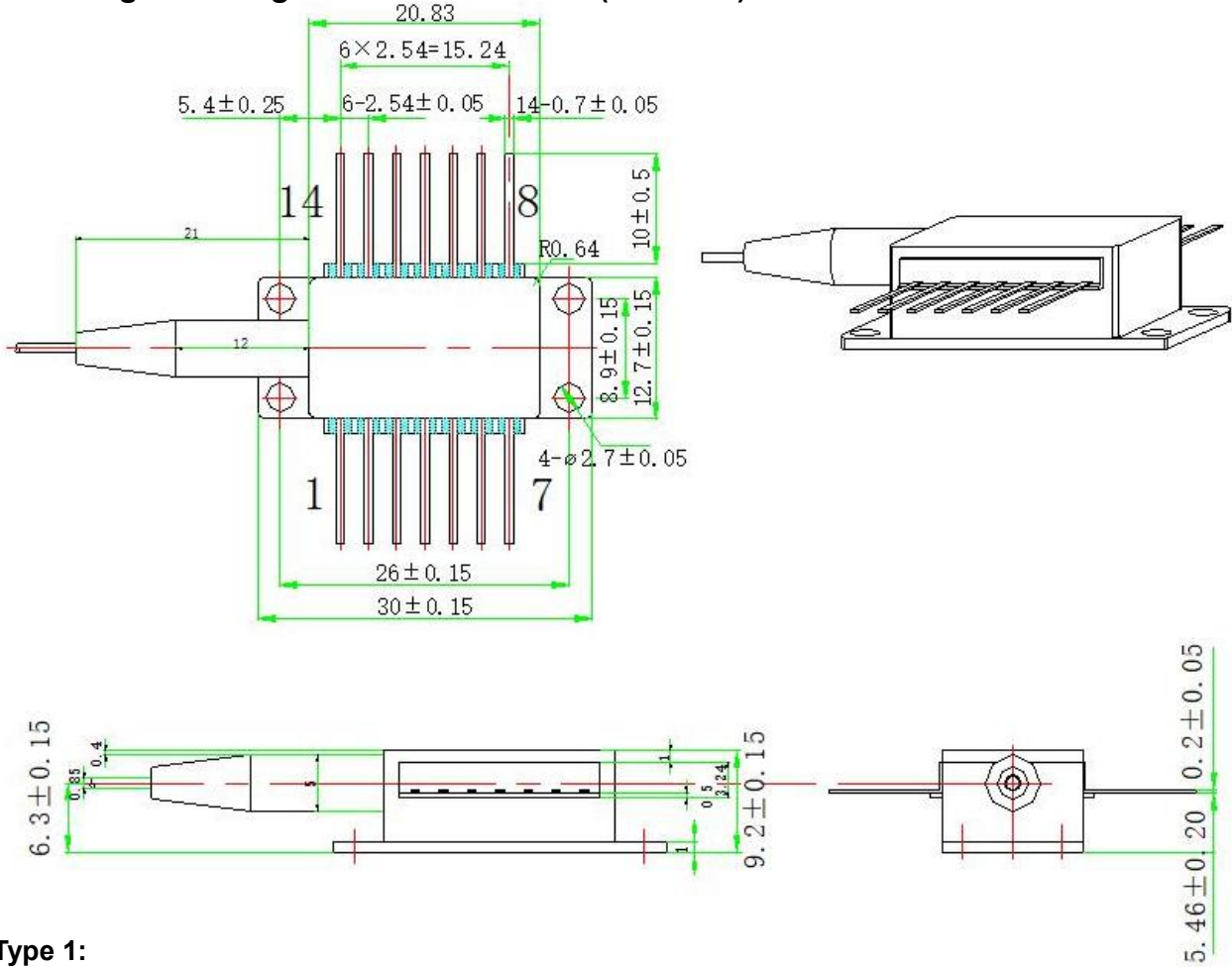
### 3. Absolute Maximum Ratings:

Parameter	Symbol	Condition	Min.	Max.	Unit
Laser forward current	$I_F$	-	-	400	mA
Reverse voltage	$V_R$	CW	-	-2.0	V
ESD Voltage	-	-	500	-	V
Operating temperature	$T_{OP}$	Case temperature	0	+70	°C
Storage temperature	$T_{STG}$	Ambient temperature	-40	+85	°C

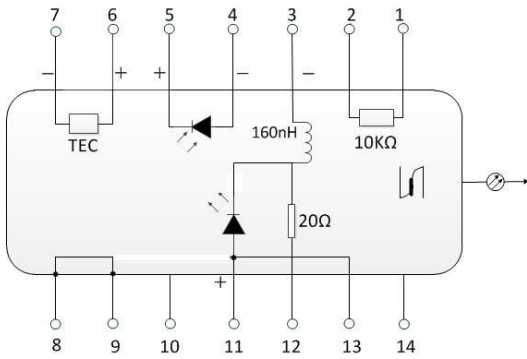
### 4. Optical-Electro Characteristics( $T=25^{\circ}\text{C}$ , $I_F = I_{OP}$ ):

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Operating wavelength	$\lambda_C$	CW, 25°C	1540	1550	1560	nm
Optical output power	$P_F$	SM Fiber	40	-	-	mW
Threshold current	$I_{TH}$	25°C	14	20	50	mA
Operating current	$I_{OP}$	CW	-	200	300	mA
Operating voltage	$V_{OP}$	25°C	-	-	3.0	V
Side mode suppression ratio	SMSR	-	35	-	-	dB
TEC Current	$I_{TEC}$	-	-1.5	-	2.5	A
TEC Voltage	$V_{TEC}$	-	-2.5	-	3.8	V
Thermistor resistance	$R_{TH}$	25°C	9.5	10	10.5	kΩ
Thermistor B-value	$\beta$	25°C/80°C	-	3950	-	K

**5. Package Drawing&PIN-OUT Definition(Unit:mm):**

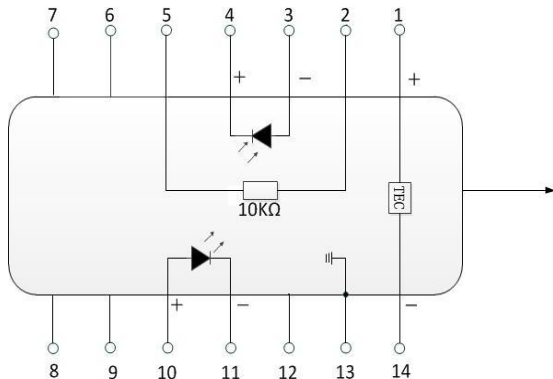


**Type 1:**



PIN	Description	PIN	Description
1	Thermistor	14	NC
2	Thermistor	13	Laser Anode(+)
3	LD Cathode(-)	12	Laser Cathode(-)
4	PD Anode (+)	11	Laser Anode(+)
5	PD Cathode(-)	10	NC
6	TEC(+)	9	Case Ground
7	TEC(-)	8	Case Ground

**Type 2**



PIN	Description	PIN	Description
1	TEC(+)	14	TEC(-)
2	Thermistor	13	Case Ground
3	PD Monitor Anode (-)	12	NC
4	PD Monitor Cathode (+)	11	Laser Cathode (-)
5	Thermistor	10	Laser Anode (+)
6	NC	9	NC
7	NC	8	NC